

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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2N6426 is a Preferred Device

Darlington Transistors

NPN Silicon

Features

• These are Pb-Free Devices*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V _{CEO}	40	Vdc
Collector - Base Voltage	V _{CBO}	40	Vdc
Emitter – Base Voltage	V _{EBO}	12	Vdc
Collector Current – Continuous	I _C	500	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	625 5.0	mW mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS

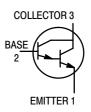
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	°C/W

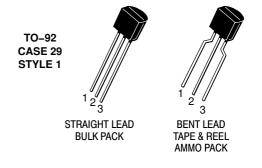
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



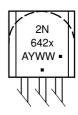
ON Semiconductor®

http://onsemi.com





MARKING DIAGRAM



x = 6 or 7

A = Assembly Location

Y = Year

WW = Work Week

= Pb–Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Collector – Emitter Breakdown Voltage, (Note 1) $(I_C = 10 \text{ mAdc}, V_{BE} = 0)$		V _{(BR)CEO}	40	-	_	Vdc
Collector – Base Breakdown Voltage $(I_C = 100 \mu Adc, I_E = 0)$		V _{(BR)CBO}	40	-	-	Vdc
Emitter – Base Breakdown Voltage ($I_E = 10 \mu Adc, I_C = 0$)		$V_{(BR)EBO}$	12	-	-	Vdc
Collector Cutoff Current (V _{CE} = 25 Vdc, I _B = 0)		I _{CES}	-	-	1.0	μAdc
Collector Cutoff Current (V _{CB} = 30 Vdc, I _E = 0)		I _{CBO}	-	-	50	nAdc
Emitter Cutoff Current (V _{EB} = 10 Vdc, I _C = 0)		I _{EBO}	-	-	50	nAdc
ON CHARACTERISTICS	<u>'</u>				•	
DC Current Gain, (Note 1) (I _C = 10 mAdc, V _{CE} = 5.0 Vdc)	2N6426 2N6427	h _{FE}	20,000 10,000	- -	200,000 100,000	
$(I_C = 100 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc})$	2N6426 2N6427		30,000 20,000	- -	300,000 200,000	
$(I_C = 500 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc})$	2N6426 2N6427		20,000 14,000	- -	200,000 140,000	
Collector – Emitter Saturation Voltage ($I_C = 50$ mAdc, $I_B = 0.5$ mAdc) ($I_C = 500$ mAdc, $I_B = 0.5$ mAdc		V _{CE(sat)}	- -	0.71 0.9	1.2 1.5	Vdc
Base – Emitter Saturation Voltage (I _C = 500 mAdc, I _B = 0.5 mAdc)		V _{BE(sat)}	-	1.52	2.0	Vdc
Base – Emitter On Voltage (I _C = 50 mAdc, V _{CE} = 5.0 Vdc)		V _{BE(on)}		1.24	1.75	Vdc
SMALL-SIGNAL CHARACTERISTICS						
Output Capacitance ($V_{CB} = 10 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz}$)		C _{obo}	_	5.4	7.0	pF
Input Capacitance (V _{EB} = 1.0 Vdc, I _C = 0, f = 1.0 MHz)		C _{ibo}	-	10	15	pF
Input Impedance ($I_C = 10 \text{ mAdc}$, $V_{CE} = 5.0 \text{ Vdc}$, $f = 1.0 \text{ kHz}$)	2N6426 2N6427	h _{ie}	100 50	_ _	2000 1000	kΩ
Small–Signal Current Gain (I _C = 10 mAdc, V _{CE} = 5.0 Vdc, f = 1.0 kHz)	2N6426 2N6427	hfe	20,000 10,000	- -	- -	-
Current-Gain - High Frequency (I _C = 10 mAdc, V _{CE} = 5.0 Vdc, f = 100 MHz)	2N6426 2N6427	h _{fe}	1.5 1.3	2.4 2.4	- -	-
Output Admittance (I _C = 10 mAdc, V _{CE} = 5.0 Vdc, f = 1.0 kHz)		h _{oe}	-	-	1000	μmhos
Noise Figure (I _C = 1.0 mAdc, V_{CE} = 5.0 Vdc, R_S = 100 k Ω , f = 1.0 kHz)		NF	-	3.0	10	dB

^{1.} Pulse Test: Pulse Width $\leq 300 \,\mu\text{s}$; Duty Cycle $\leq 2.0\%$.

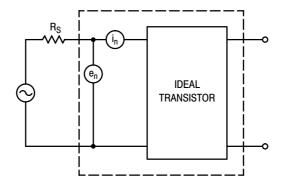


Figure 1. Transistor Noise Model

NOISE CHARACTERISTICS

 $(V_{CE} = 5.0 \text{ Vdc}, T_A = 25^{\circ}C)$

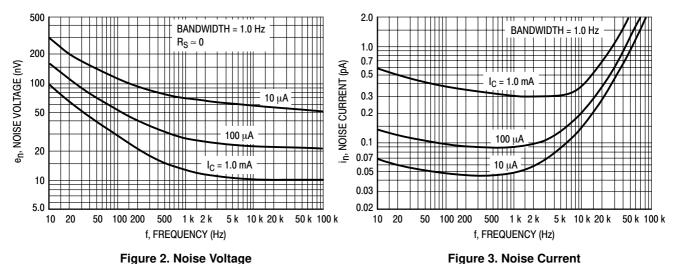


Figure 2. Noise Voltage

200 V_T, TOTAL WIDEBAND NOISE VOLTAGE (nV) BANDWIDTH = 10 Hz TO 15.7 kHz 12 BANDWIDTH = 10 Hz TO 15.7 kHz 100 NF, NOISE FIGURE (dB) 10 70 $I_C = 10 \mu A$ 10 μA 8.0 50 100 μΑ 6.0 100 μΑ 30 4.0 I_C = 1.0 mA 20 1.0 mA 2.0 1.0 2.0 100 200 500 2.0 1000 20 50 1000 1.0 5.0 20 50 100 500 R_S , SOURCE RESISTANCE ($k\Omega$) R_S , SOURCE RESISTANCE ($k\Omega$)

Figure 4. Total Wideband Noise Voltage

Figure 5. Wideband Noise Figure

SMALL-SIGNALCHARACTERISTICS

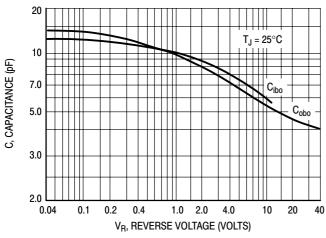


Figure 6. Capacitance

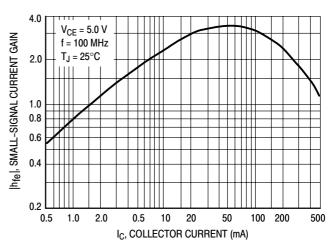


Figure 7. High Frequency Current Gain

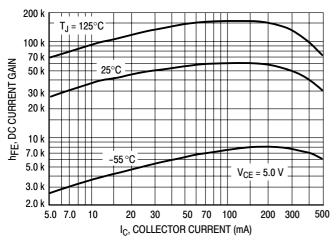


Figure 8. DC Current Gain

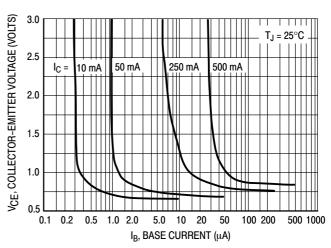


Figure 9. Collector Saturation Region

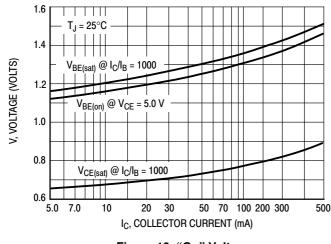


Figure 10. "On" Voltages

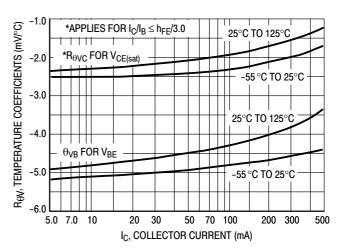


Figure 11. Temperature Coefficients

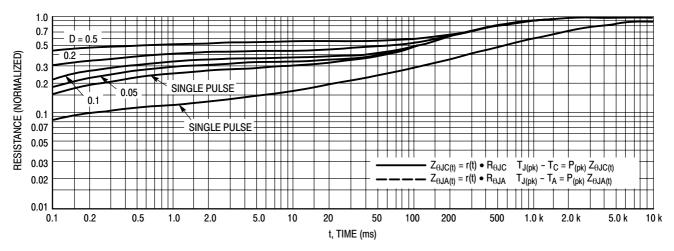


Figure 12. Thermal Response

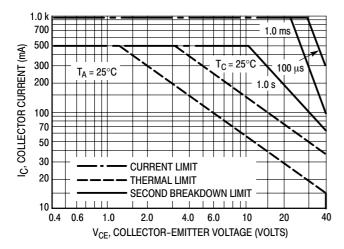
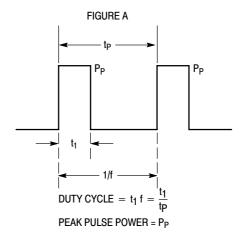


Figure 13. Active Region Safe Operating Area



Design Note: Use of Transient Thermal Resistance Data

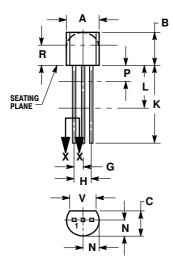
ORDERING INFORMATION

Device	Package	Shipping [†]
2N6426G	TO-92 (Pb-Free)	5,000 Units / Bulk
2N6426RLRAG	TO-92 (Pb-Free)	2,000 / Tape & Ammo
2N6427G	TO-92 (Pb-Free)	5,000 Units / Bulk
2N6427RLRAG	TO-92 (Pb-Free)	2,000 / Tape & Ammo

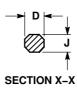
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 ISSUE AM



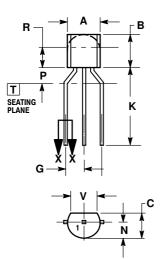
STRAIGHT LEAD **BULK PACK**



NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED
- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.115		2.93	
٧	0.135		3.43	



BENT LEAD TAPE & REEL AMMO PACK



NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: MILLIMETERS.
 CONTOUR OF PACKAGE BEYOND
- DIMENSION R IS UNCONTROLLED
- LEAD DIMENSION IS UNCONTROLLED IN PAND BEYOND DIMENSION K MINIMUM.

	MILLIMETERS		
DIM	MIN	MAX	
Α	4.45	5.20	
В	4.32	5.33	
С	3.18	4.19	
D	0.40	0.54	
G	2.40	2.80	
J	0.39	0.50	
K	12.70		
N	2.04	2.66	
Р	1.50	4.00	
R	2.93		
٧	3.43		

STYLE 1:

PIN 1 FMITTER

BASE

COLLECTOR

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